



12500 TI Boulevard, MS 8640, Dallas, Texas 75243

**PCN#20151211001**

**Quality TI Chengdu (CDAT) as an additional Assembly & Test site for select devices  
Change Notification / Sample Request**

**Date:** 12/14/2015  
**To:** Newark/Farnell PCN

Dear Customer:

This is an announcement of a change to a device that is currently offered by Texas Instruments. The details of this change are on the following pages.

We request you acknowledge receipt of this notification within **30** days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance of the change. If you require samples or additional data to support your evaluation, please request within 30 days.

The changes discussed within this PCN will not take effect any earlier than **90** days from the date of this notification, unless customer agreement has been reached on an earlier implementation of the change. This notification period is per TI's standard process.

This notice does not change the end-of-life status of any product. Should product affected be on a previously issued product withdrawal/discontinuance notice, this notification does not extend the life of that product or change the life time buy offering/discontinuance plan.

For questions regarding this notice, contact your local Field Sales Representative or the PCN Manager ([PCN\\_ww\\_admin\\_team@list.ti.com](mailto:PCN_ww_admin_team@list.ti.com)).

Sincerely,

PCN Team  
SC Business Services

**20151211001**  
**Attachment: 1**

**Products Affected:**

The devices listed on this page are a subset of the complete list of affected devices. According to our records, these are the devices that you have purchased within the past twenty-four (24) months. The corresponding customer part number is also listed, if available.

<b>DEVICE</b>	<b>CUSTOMER PART NUMBER</b>
TPD4E110DPWR	null
TPD4E6B06DPWR	null
TS3A227ERVAR	null

Technical details of this Product Change follow on the next page(s).

<b>PCN Number:</b>	20151211001		<b>PCN Date:</b>	12/14/2015	
<b>Title:</b>	Quality TI Chengdu (CDAT) as an additional Assembly & Test site for the list of devices shown below				
<b>Customer Contact:</b>	<a href="#">PCN Manager</a>	<b>Dept:</b>	Quality Services		
<b>Proposed 1<sup>st</sup> Ship Date:</b>	3/14/2016	<b>Estimated Sample Availability:</b>	Provided upon Request		
<b>Change Type:</b>					
<input checked="" type="checkbox"/>	Assembly Site	<input type="checkbox"/>	Assembly Process	<input type="checkbox"/>	Assembly Materials
<input type="checkbox"/>	Design	<input type="checkbox"/>	Electrical Specification	<input type="checkbox"/>	Mechanical Specification
<input type="checkbox"/>	Test Site	<input type="checkbox"/>	Packing/Shipping/Labeling	<input type="checkbox"/>	Test Process
<input type="checkbox"/>	Wafer Bump Site	<input type="checkbox"/>	Wafer Bump Material	<input type="checkbox"/>	Wafer Bump Process
<input type="checkbox"/>	Wafer Fab Site	<input type="checkbox"/>	Wafer Fab Materials	<input type="checkbox"/>	Wafer Fab Process
		<input type="checkbox"/>	Part number change		
<b>PCN Details</b>					
<b>Description of Change:</b>					
<p>Texas Instruments is pleased to announce the qualification of TI Chengdu (CDAT) as an additional Assembly &amp; Test site for the list of devices shown below. There are no device construction differences between the 2 sites.</p> <p>Test coverage, insertions, conditions will remain consistent with current testing and verified with test MQ.</p>					
<b>Reason for Change:</b>					
Continuity of Supply					
<b>Anticipated impact on Fit, Form, Function, Quality or Reliability (positive / negative):</b>					
None					
<b>Anticipated impact on Material Declaration</b>					
<input checked="" type="checkbox"/>	No Impact to the Material Declaration	<input type="checkbox"/>	Material Declarations or Product Content reports are driven from production data and will be available following the production release. Upon production release the revised reports can be obtained from the <a href="#">TI ECO website</a> .		
<b>Changes to product identification resulting from this PCN:</b>					
<b>Assembly Site</b>	<b>Assembly Site Origin (22L)</b>	<b>Assembly Country Code (21L)</b>	<b>Assembly City</b>		
TI Clark	QAB	PHL	Angeles City		
JCET	JCE	CHN	Jiangyin		
<b>TI Chengdu</b>	<b>CDA</b>	<b>CHN</b>	<b>Chengdu</b>		
Sample product shipping label (not actual product label)					



MADE IN: Malaysia  
2DC: 2Q:

MSL 2 /260C/1 YEAR	SEAL DT
MSL 1 /235C/UNLIM	03/29/04

OPT:  
ITEM:

LBL: 5A (L)T0:1750



(1P) SN74LS07NSR  
(Q) 2000 (D) 0336  
(31T) LOT: 3959047MLA  
(4W) TKY (1T) 7523483SI2  
(P)  
(2P) REV: (V) 0033317  
(20L) CSO: SHE (21L) CCO:USA  
(22L) ASO: MLA (23L) ACO: MYS

**Topside Device marking:**

Assembly site code for QAB= I

Assembly site code for JCE= F

**Assembly site code for CDA = 8**

**Product Affected**

TS3A227ERVAR	TPD4E110DPWR	TPD4E6B06DPWR
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T1 Information  
Selective Disclosure

**Qualification Report**

TS3A227ERVAR - 2nd Source A-T site (CDAT)  
Approve Date 19-Oct-2015

**Product Attributes**

Attributes	Qual Device: TS3A227ERVAR	QBS Product Reference: TS3A227ERVAR	QBS Product Reference: TS3A227ERVAR	QBS Process Reference: TPS2543QRTE	QBS Package Reference: TPS53641RSBR
Assembly Site	CHENGDU AT	CLARK AT	CLARK AT (UV)	CLARK-AT	CHENGDU AT
Package Family	VQFN	QFN	QFN	TQFN	WQFN
Flammability Rating	-	UL 94 V-0	UL 94 V-0	UL 94 V-0	UL 94 V-0
Wafer Fab Supplier	RFAB	RFAB	RFAB	RFAB	RFAB
Wafer Process	LBC7	LBC7	LBC7	LBC7	LBC7

- QBS: Qual By Similarity  
- Qual Device TS3A227ERVAR is qualified at 2

**Qualification Results**

Data Displayed as: Number of lots / Total sample size / Total failed



Type	Test Name / Condition	Duration	Qual Device: TS3A227ERVAR	QBS Product Reference: TS3A227ERVAR	QBS Product Reference: TS3A227ERVAR	QBS Process Reference: TPS2543QRTE	QBS Package Reference: TPS53641RSBR
AC	Autoclave 121C	96 Hours	1/77/0	1/77/0	-	3/231/0	3/230/0
ED	Electrical Distributions (Cpk>1.67)	Room, hot, and cold test	-	-	-	3/90/0	-
ED	Electrical Characterization	Per Datasheet Parameters	-	Pass	Pass	-	-
ELFR	Early Life Failure Rate, 150C	24 Hours	-	-	-	3/2640/0	-
HAST	Biased HAST 130C/85%RH	96 Hours	1/77/0	-	-	3/231/0	-
HBM	ESD - HBM	4000 V	-	-	1/3/0	1/3/0	-
CDM	ESD - CDM	1500 V	-	-	1/3/0	1/3/0	-
HTOL	Life Test, 150C	408 Hours	-	-	-	3/231/0	-
HTSL	High Temp. Storage Bake, 170C	420 Hours	1/77/0	-	-	-	-
HTSL	High Temp. Storage Bake, 175C	500 Hours	-	-	-	3/149/0	-
LU	Latch-up	(per JESD78)	-	-	1/6/0	1/6/0	-
PD	Physical Dimensions	--	Pass	Pass	-	Pass	Pass
SD	Surface Mount Solderability	Pb Free	1/22/0	2/44/0	-	2/30/0	-
SD	Surface Mount Solderability	Pb	1/22/0	-	-	-	-
TC	Temperature Cycle, -65/150C	500 Cycles	1/77/0	-	-	3/231/0	3/231/0
WBP	Bond Pull	Wires	1/76/0	1/76/0	-	-	-
WBS	Ball Bond Shear	Wires	1/76/0	1/76/0	-	-	-

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock and HTSL, as applicable  
- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/900 Hours, and 155C/240 Hours  
- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours  
- The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles

## Qualification Report

### TPD4E6B06DPWR (JCET to CDAT) (new package for CDAT) Approve Date 09-Dec-2015

#### Product Attributes

Attributes	Qual Device: TPD4E6B06DPW	QBS Package Reference: TPD1E10B09DPYR
Assembly Site	CDAT	CHENGDU
Package Family	SON 0.8 X 0.8 MM	X2SON
Flammability Rating	-	UL 94 V-0
Wafer Fab Supplier	CFAB	CFAB
Wafer Process	VDIODE.BD	VDIODE

- QBS: Qual By Similarity
- Qual Device TPD4E6B06DPW is qualified at LEVEL1-260CG
- Device TPD4E6B06DPW contains multiple dies.

#### Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Type	Test Name / Condition	Duration	Qual Device: TPD4E6B06DPW	QBS Package Reference: TPD1E10B09DPYR
AC	Autoclave 121C	96 Hours	3/231/0	3/231/0
ED	Electrical Characterization	Per Datasheet Parameters	-	Pass
HAST	Biased HAST, 130C/85%RH	96 Hours	-	3/231/0
HBM	ESD - HBM	2000 V	-	-
CDM	ESD - CDM	500 V	-	-
HTOL	Life Test, 150C	300 Hours	-	-
HTSL	High Temp. Storage Bake, 170C	420 Hours	3/231/0	3/231/0
PD	Physical Dimensions	--	3/15/0	3/15/0
SD	Solderability (Post 8 Hour Steam)	Pb Free	3/66/0	-
SD	Surface Mount Solderability	Pb Free	-	3/66/0
TC	Temperature Cycle, -65/150C	500 Cycles	3/231/0	3/231/0

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
  - The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
  - The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
  - The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles
- Quality and Environmental data is available at TI's external Web site: <http://www.ti.com/>

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	<a href="mailto:PCNAmericasContact@list.ti.com">PCNAmericasContact@list.ti.com</a>
Europe	<a href="mailto:PCNEuropeContact@list.ti.com">PCNEuropeContact@list.ti.com</a>
Asia Pacific	<a href="mailto:PCNAsiaContact@list.ti.com">PCNAsiaContact@list.ti.com</a>
Japan	<a href="mailto:PCNJapanContact@list.ti.com">PCNJapanContact@list.ti.com</a>